INTERSIL

IM5600/IM5610
256 Bit Bipolar Read Only Memory

FEATURES

- Uses Patented AIM Programming Element for
  - Superior Reliability
  - High Programming Yield
  - Fast Programming Speed < 1 sec
  - TTL Processing Compatibility
- Low Power Consumption 1.5 mW/bit
- Operating Speed
  - Address to Output — 50nS
  - Chip Enable to Output — 40nS
- Large Output Drive — 16mA @ 0.45V
- TTL Compatible Inputs & Outputs
- Two Output Designs
  - 5600 Open Collector
  - 5610 Active Pull-up
- Chip Enable Facilitates Memory Expansion and Use in Bus Organized Systems

APPLICATIONS

- Code Conversion
- Logic Implementation
- Microprogramming
- Look-up Tables
- Control of Sequential Circuits
- Character Generation

GENERAL DESCRIPTION

The Intersil IM5600 and IM5610 are high speed, electrically programmable, fully decoded, bipolar 256 bit read only memories organized as 32 words by 8 bits. On-chip address decoding, chip enable input and uncomitted collector or three-state outputs provide for simplified memory expansion and use in bus organized systems.

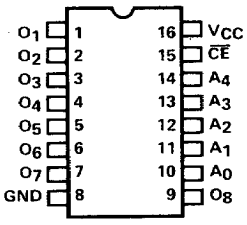
Unprogrammed AIM elements are sensed as ZERO's or low logic levels at the outputs. Programming with a commercially available programmer irreversibly converts selected elements in the array so that they are sensed as ONE's or high logic levels.

The following companies make programmers approved by Intersil:

1. Data I/O Corp., P.O. Box 1603, Bellevue, Wash. 98009
2. PRO-LOG Corp., 2411 Garden Rd., Monterey, CA 93940

Detailed programming specifications for all Intersil PROMs are presented in the Intersil BIPOLAR PROM PROGRAMMING SPECIFICATION Data Sheet.

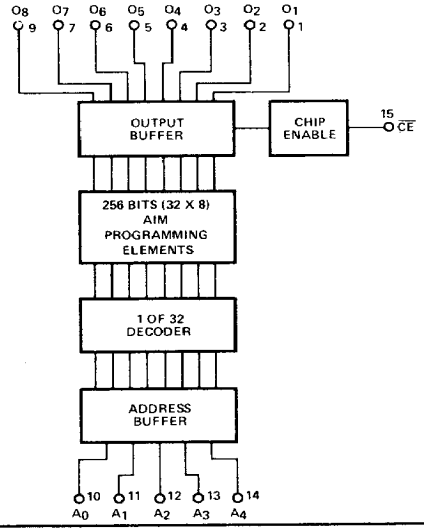
CONNECTION DIAGRAM



TOP VIEW

(outline dwgs JE, PE)

BLOCK DIAGRAM



ORDERING INFORMATION

PART NUMBER	PACKAGE	TEMPERATURE RANGE	ORDER NUMBER
IM5600	16 Pin Flatpack	0°C to +75°C Commercial −55°C to +125°C Military	IM5600CFE IM5600MFE*
	16 Pin Plastic DIP	0°C to +75°C	IM5600CPE
	16 Pin Cerdip DIP	0°C to +75°C Commercial −55°C to +125°C Military	IM5600CJE IM5600MJE*
IM5610	16 Pin Flatpack	0°C to +75°C Commercial −55°C to +125°C Military	IM5610CFE IM5610MFE*
	16 Pin Plastic DIP	0°C to +75°C	IM5610CPE
	16 Pin Cerdip DIP	0°C to +75° C Commercial −55°C to +125°C Military	IM5610CJE IM5610MJE*

* If 883B processing is desired add /883B to order number.

TRUTH TABLE

ADDRESS INPUTS A_0–A_4	$\overline{CE}$	ANY OUTPUT O_1–O_8
Any one of 32 possible addresses.	L	H—if the bit uniquely associated with this output and address has been electrically programmed. L—if it has not been programmed.
Any one of 32 possible addresses.	H	All outputs are forced to a high impedance state regardless of the address.

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ABSOLUTE MAXIMUM RATINGS

Supply Voltage ..... +7.0V
Input Voltage Applied ..... −1.5V to +5.5V
Output Voltage Applied ..... −0.5V to +V_{CC}
Output Voltage Applied (Programming Only) 28V
Current Into Output (Programming Only) ..... 210 mA
Storage Temperature ..... −65°C to +150°C
Operating Temperature Range*
(IM5600C and IM5610C) ..... 0°C to +75°C
(IM5600M and IM5610M) ..... −55°C to +125°C

*Operating temperature is defined as ambient temperature for the DIP and case temperature for the flatpack. Case temperature is measured directly below the die.

DC CHARACTERISTICS

SYMBOL	CHARACTERISTICS	LIMITS V_{CC} = 5.0V ±5% T = 0°C to +75°C			LIMITS V_{CC} = 5.0V ±10% T = −55°C to +125°C			UNITS	CONDITIONS
		MIN	TYP	MAX	MIN	TYP	MAX		
I_{FA}	Address Input Load Current		−0.63	−1.0		−0.63	−1.0	mA	V_A = 0.4V
I_{FE}	Chip Enable Input Load Current		−0.63	−1.0		−0.63	−1.0		$V_{\overline{CE}}$ = 0.4V
I_{RA}	Address Input Leakage Current		5.0	40		5.0	60	µA	V_A = 4.5V
I_{RE}	Chip Enable Input Leakage Current		5.0	40		5.0	60		$V_{\overline{CE}}$ = 4.5V
V_{OL}	Output Low Voltage		0.3	0.45		0.3	0.45	V	I_{OL} = 16 mA V_{CE} = 0.4V '0' bit is addressed.
V_{IL}	Input Low Voltage			0.8			0.8		
V_{IH}	Input High Voltage	2.0			2.0				
V_C	Input Clamp Voltage		−0.9	−1.5		−0.9	−1.5		I_{IN} = −10 mA
BV_{IN}	Input Breakdown Voltage	5.5	6.5		5.5	6.5			I_{IN} = 1.0 mA
I_{CC}	Power Supply Current		75	100		75	100	mA	Inputs Either Open or at Ground
I_O (High R State)	Output Leakage Current		<1.0	40		<1.0	100	µA	V_O = 5.5V, V_{CE} = 2.4V
I_O (High R State)	Output Leakage Current		<−1.0	−40		<−1.0	−100		V_O = 0.4V, V_{CE} = 2.4V
C_{IN}	Input Capacitance		5.0			5.0		pF	V_{IN} = 2.0V, V_{CC} = 0V
C_{OUT}	Output Capacitance		7.0			7.0			V_O = 2.0V, V_{CC} = 0V

The following are guaranteed characteristics of the output high level state when the chip is enabled ($\overline{CE}$ = 0.4V) and a programmed bit is addressed. These characteristics cannot be tested prior to programming but are guaranteed by design.

I_{OLK}	Output Leakage Current		<1.0	100		<1.0	100	µA	V_O = 5.5V, $V_{\overline{CE}}$ = 0.4V
V_{OH} (IM5610)	Output High Voltage	2.4	3.2		2.4	3.2		V	I_{OH} = −1.0 mA (IM5610M) I_{OH} = −2.4 mA (IM5610C)
I_{SC} (IM5610)	Output Short Circuit	−15	−30	−60	−15	−30	−60	mA	V_O = 0V

NOTE 1: Typical characteristics are for V_{CC} = 5.0V, T_A = 25°C.

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SWITCHING CHARACTERISTICS

SYMBOL	CHARACTERISTIC	LIMITS V_{CC} = 5V T_A = 25°C		LIMITS V_{CC} = 5V ±5% T_A = 0°C to +75°C		LIMITS V_{CC} = 5V ±10% T_A = −55°C to +125°C		UNITS
		MIN	MAX	MIN	MAX	MIN	MAX	
t_{aa}	Address Access Time	20	50	20	65	20	75	ns
t_{dis}	Output Disable Time*	10	40	10	50	10	60	
t_{en}	Output Enable Time*	5	40	5	50	5	60	

* Output disable time is the time taken for the output to reach a high resistance state when the chip enable is taken high. Output enable time is the time taken for the output to become active when the chip enable is taken low. The high resistance state is defined as a point on the output waveform equal to a ΔV of 0.5V from the active output level.

SWITCHING WAVEFORMS

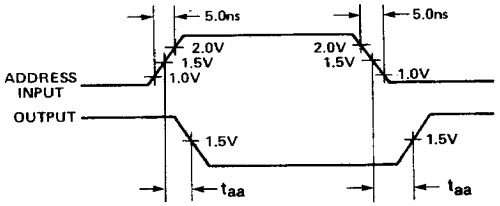

FIGURE 1: Access Time Via Address Input

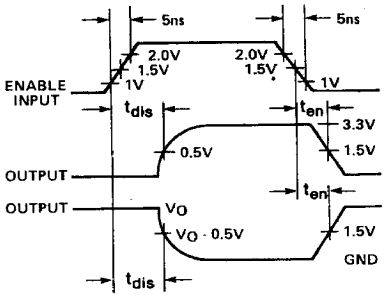

FIGURE 2: Output Disable And Enable Time

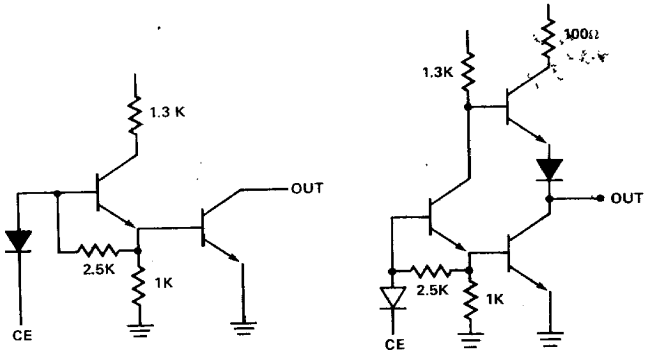

FIGURE 3: Output Stage Schematics

SWITCHING TIME TEST CONDITIONS

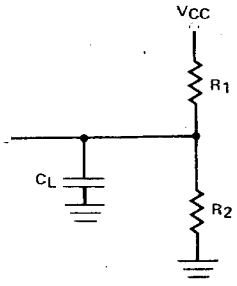

FIGURE 4: Output Load Circuit

SWITCHING PARAMETER	IM5600 R_1	IM5600 R_2	IM5600 C_L	IM5610 R_1	IM5610 R_2	IM5610 C_L
t_{aa}	300Ω	600Ω	30 pF	300Ω	600Ω	30 pF
t_{dis} '1'	∞	3.3 KΩ	10 pF	∞	600Ω	10 pF
t_{dis} '0'	300Ω	600Ω	10 pF	300Ω	600Ω	10 pF
t_{en} '1'	∞	3.3 KΩ	30 pF	∞	600Ω	30 pF
t_{en} '0'	300Ω	600Ω	30 pF	300Ω	600Ω	30 pF

INPUT CONDITIONS

Amplitude — 0V to 3V
Rise and Fall Time — 5 ns From 1V to 2V
Frequency — 1 MHz

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